



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

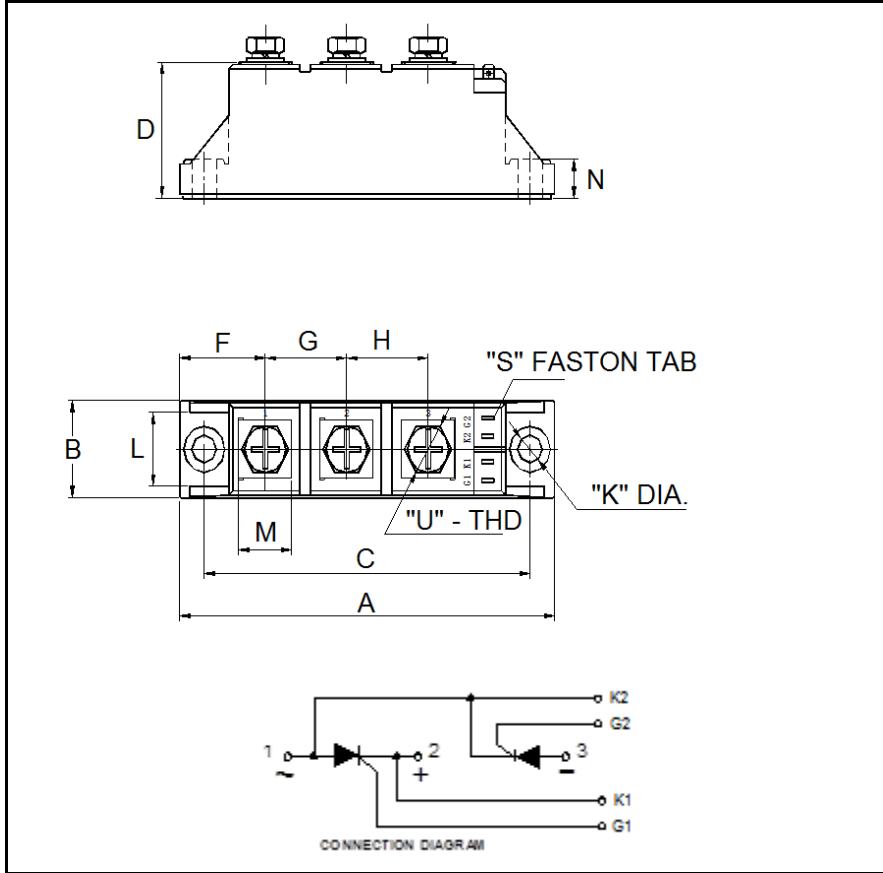
Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



Powerex, Inc., 173 Pavilion Lane, Youngwood, Pennsylvania 15697 (724) 925-7272
<http://www.pwr.com>

POW-R-BLOK™
Dual SCR Isolated Module
90 Amperes / Up to 1800 Volts



Description:

Powerex Dual SCR Modules are designed for use in applications requiring phase control and isolated packaging. The modules are isolated for easy mounting with other components on a common heatsink.

Features:

- Electrically Isolated Heatsinking
- Compression Bonded for Increased Power Cycling Capability
- Low Thermal Impedance for Improved Current Capability
- RoHS Compliant
- UL Recognized (E78240)

Benefits:

- No Additional Insulation Components Required
- Easy Installation
- No Clamping Components Required
- Reduce Engineering Time

Applications:

- Bridge Circuits
- AC & DC Motor Drives
- Battery Supplies
- Power Supplies
- Large IGBT Circuit Front Ends
- Lighting Control
- Heat & Temperature Control
- Welders

CD43_90C Outline Dimensions

Dimension	Inches	Millimeters
A	3.62	92
B	0.83	21
C	3.15	80
D	1.18	30
F	0.83	21
G	0.79	20
H	0.79	20
K	0.24	6.2
L	0.63	16
M	0.51	13
N	0.33	8.5
S	0.11 x .02	2.8 x 0.5
U	M5	M5

Note: Dimensions are for reference only.

CD43_90C
Dual SCR Isolated
POW-R-BLOK™ Module
90 Amperes / Up to 1800 Volts

Ordering Information:

Select the complete nine digit module part number from the table below.
 Example: CD431690C is a 1600Volt, 90 Ampere Dual SCR Isolated POW-R-BLOK™ Module

Type	Voltage Volts (x100)	Current Amperes	Version
CD43	08	90	C
	12		
	14		
	16		
	18		

Absolute Maximum Ratings

Characteristics	Conditions	Symbol		Units
Repetitive Peak Forward and Reverse Blocking Voltage		V_{DRM} & V_{RRM}	up to 1800	V
Non-Repetitive Peak Reverse Blocking Voltage ($t < 5$ msec)		V_{RSM}	$V_{RRM} + 200$	V
RMS Forward Current	180° Conduction, $T_C=85^\circ\text{C}$	$I_{T(RMS)}$	141	A
Average Forward Current	180° Conduction, $T_C=85^\circ\text{C}$	$I_{T(AV)}$	90	A
Peak One Cycle Surge Current, Non-Repetitive	50 Hz, 60% V_{RRM} reapplied, $T_j=125^\circ\text{C}$	I_{TSM}	2000	A
I^2t for Fusing for One Cycle, 10 milliseconds	50 Hz, 60% V_{RRM} reapplied, $T_j=125^\circ\text{C}$	I^2t	20,400	$\text{A}^2 \text{sec}$
Maximum Rate-of-Rise of On-State Current, (Repetitive)	$T_j=125^\circ\text{C}$	di/dt	100	$\text{A}/\mu\text{s}$
Operating Temperature		T_J	-40 to +125	$^\circ\text{C}$
Storage Temperature		T_{stg}	-40 to +125	$^\circ\text{C}$
Max. Mounting Torque, M5 Mounting Screw on Terminals			35 4	in.-Lb. Nm
Max. Mounting Torque, Module to Heatsink			53 6	in.-Lb. Nm
Module Weight, Typical			160 5.64	g oz.
V Isolation @ 25C	50 – 60 Hz, 1 minute	V_{rms}	2500	V

Information presented is based upon manufacturers testing and projected capabilities.
This information is subject to change without notice.
The manufacturer makes no claim as to the suitability of use, reliability, capability,
or future availability of this product.

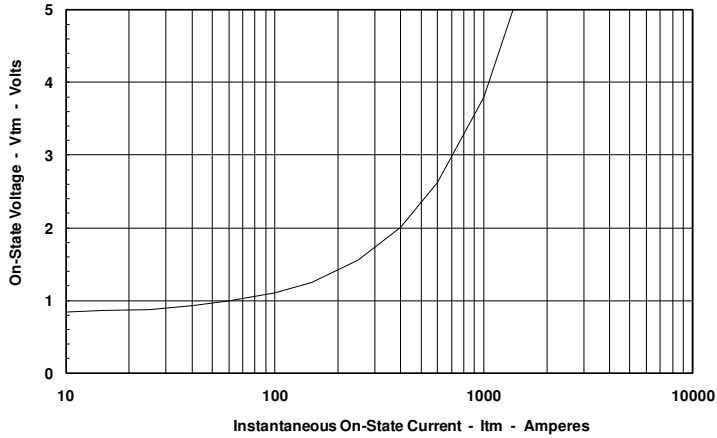
Electrical Characteristics, T_J=25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Max.	Units
Repetitive Peak Forward Leakage Current	I _{DRM}	Up to V _{DRM} , T _J =125°C		10	mA
Repetitive Peak Reverse Leakage Current	I _{RRM}	Up to V _{RRM} , T _J =125°C		10	mA
Peak On-State Voltage	V _{TM}	I _{TM} =270A		1.70	V
Threshold Voltage, Low-level	V _{(TO)1}	T _J = 125°C, I = 16.7% x πI _{T(AV)} to πI _{T(AV)}		0.8	V
Slope Resistance, Low-level	r _{T1}			3.01	mΩ
Minimum dV/dt	dV/dt	T _J =125°C, V _{DM} = 0.67 V _{DRM}	800		V/μs
Gate Trigger Current	I _{GT}	T _J = 25°C, V _D =12V, I _A = 1 A	30	100	mA
Gate Trigger Voltage	V _{GT}	T _J = 25°C, V _D =12V, I _A = 1 A	1.0	2.5	Volts
Holding Current	I _H	T _J = 25°C, V _D =12V, I _A = 1 A	20	100	mA

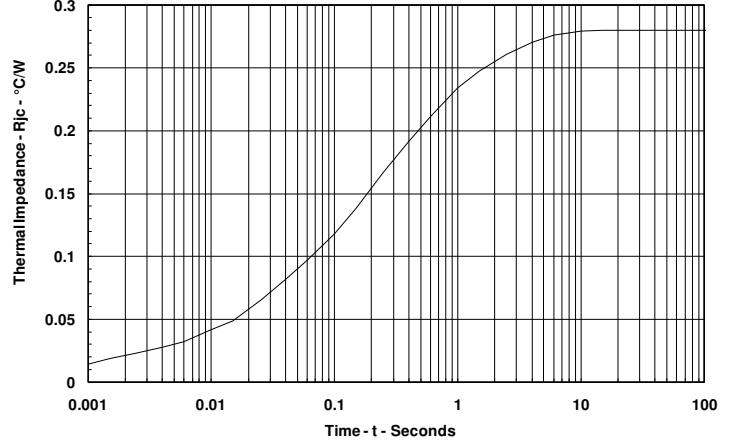
Thermal Characteristics

Characteristics	Symbol		Max.	Units
Thermal Resistance, Junction to Case DC Operation	R _{ΘJ-C}	Per Junction, both conducting	0.28	°C/W
Thermal Resistance, Case to Sink Lubricated	R _{ΘC-S}	Per Module	0.15	°C/W

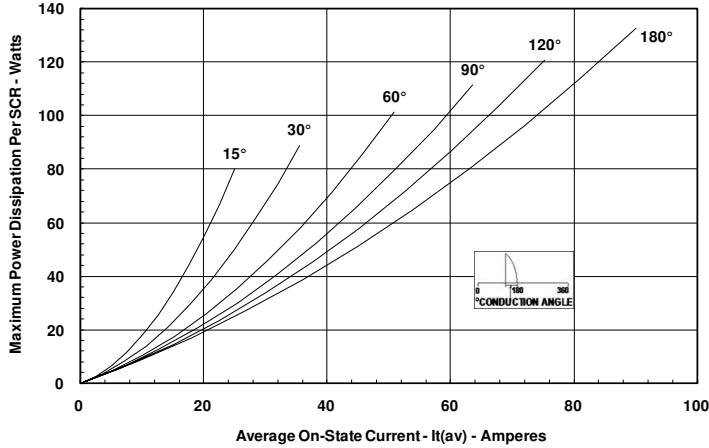
Maximum On-State Forward Voltage Drop
 (T_j = 125 °C)



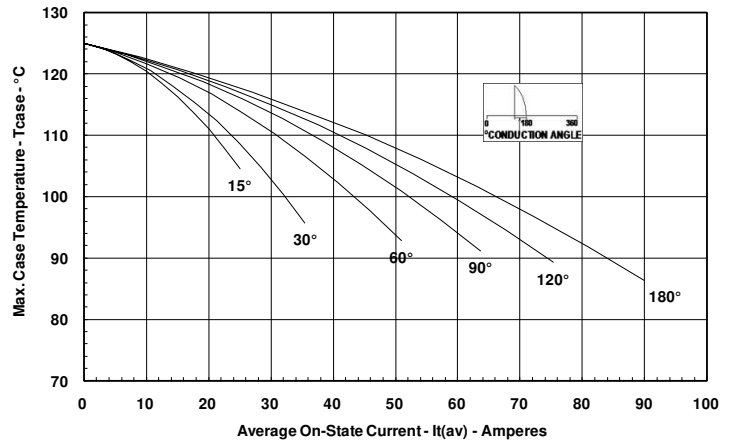
Maximum Transient Thermal Impedance
 (Junction to Case)



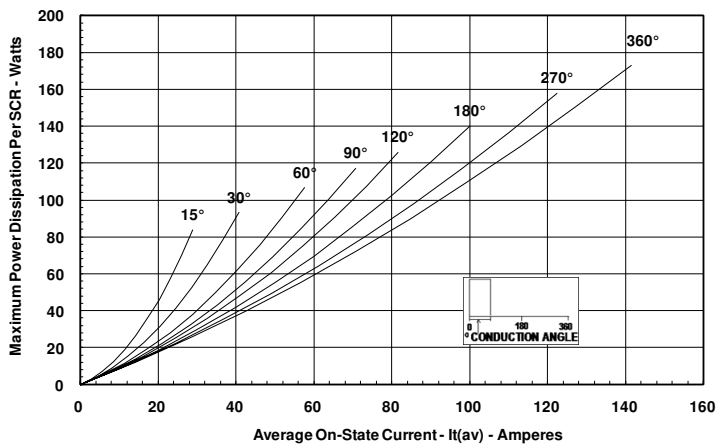
Maximum On-State Power Dissipation
 (Sinusoidal Waveform)



Maximum Allowable Case Temperature
 (Sinusoidal Waveform)



Maximum On-State Power Dissipation
 (Rectangular Waveform)



Maximum Allowable Case Temperature
 (Rectangular Waveform)

